## SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

# **5-Line Transient Voltage** Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-88 package.

#### **Features**

- Protects up to 5-Line in a Single SC-88 Package
- Peak Power Dissipation 100 W (8 x 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8 kV (Contact)
- Flammability Rating of UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable
- Pb-Free Packages are Available\*

#### Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

### MAXIMUM RATINGS (T<sub>.1</sub> = 25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P <sub>PK</sub> 1	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1)	100	W
TJ	Operating Junction Temperature Range	-40 to 125	°C
T <sub>STG</sub>	Storage Temperature Range	–55 to 150	°C
ΤL	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 15000	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Nonrepetitive current pulse per Figure 3.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



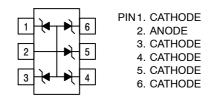
## **ON Semiconductor®**

http://onsemi.com

### **SC-88 FIVE TRANSIENT VOLTAGE SUPPRESSOR 100 W PEAK POWER**

SC-88 CASE 419B **STYLE 24** 

#### **PIN ASSIGNMENT**



### MARKING DIAGRAM



XX = Specific Device Code 6J = SMF05C6K = SZSMF12C/SMF12C 6L = SMF15C 6M = SMF24C Date Code

#### Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

## SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

#### SMF05CT1G ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 3)	6.2		7.2	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5 V		0.07	5.0	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5 A (8 x 20 μs Waveform)			9.8	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 8 A (8 x 20 μs Waveform)			12.5	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			8.0	А
Capacitance	CJ	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)		80	130	pF

### SMF12CT1G ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = $25^{\circ}$ C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			12	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 3)	13.3		15	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 12 V		0.01	0.1	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 3 A (8 x 20 μs Waveform)			21	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 6 A (8 x 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			6.0	А
Capacitance	CJ	$V_R = 0 V$ , f = 1 MHz (Line to GND)		40	60	pF

#### SMF15CT1G ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = $25^{\circ}$ C, unless otherwise specified)

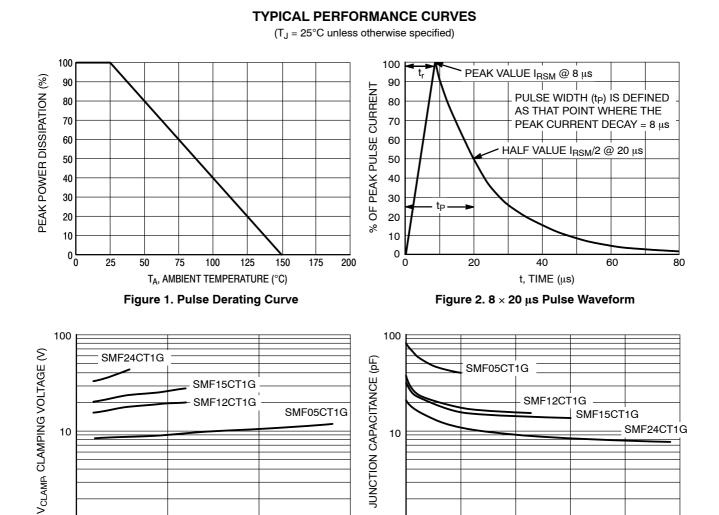
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			15	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 3)	17		19	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 15 V		0.01	1.0	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1 A (8 x 20 μs Waveform)			23	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 5 A (8 x 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			5.0	А
Capacitance	CJ	$V_R = 0 V$ , f = 1 MHz (Line to GND)		33	45	pF

#### SMF24CT1G ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = $25^{\circ}$ C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	(Note 2)			24	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1 mA, (Note 3)	26.7		32	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 24 V		0.01	1.0	μΑ
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1 A (8 x 20 μs Waveform)			40	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 2.5 A (8 x 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I <sub>PP</sub>	8 x 20 μs Waveform			2.5	А
Capacitance	CJ	$V_R = 0 V$ , f = 1 MHz (Line to GND)		21	25	pF

2. TVS devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level. 3.  $V_{BR}$  is measured at pulse test current I<sub>T</sub>. 4. Include SZ-prefix devices where applicable.

## SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G



#### **ORDERING INFORMATION**

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IPP, PEAK PULSE CURRENT (A)

Figure 3. Clamping Voltage vs Peak Pulse Current

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0

Device	Package	Shipping <sup>†</sup>
SMF05CT1G	SC-88 3,000 / Tape & I (Pb-Free)	
SMF05CT2G*	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF12CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF15CT1G	SC-88 (Pb-Free)	3,000 / Tape & Reel
SMF24CT1G	SC-88 3,000 / Tape &   (Pb-Free) (Pb-Free)	

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V<sub>BR</sub>, REVERSE VOLTAGE (V)

Figure 4. Junction Capacitance vs Reverse Voltage

15

20

25

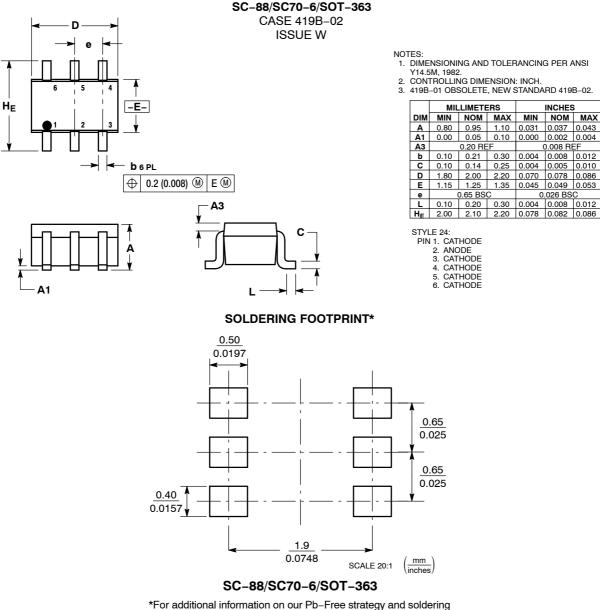
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+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*The "T2" suffix refers to an alternate tape & reel orientation.

### SMF05CT1G, SMF12CT1G, SMF15CT1G, SMF24CT1G, SZSMF12CT1G

#### PACKAGE DIMENSIONS



details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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